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Advanced CMOS Devices and Applications

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Deadline for manuscript submissions:

closed (28 February 2023)

Message from the Guest Editors

We are pleased to invite you to submit your abstracts in the fields related to advanced CMOS transistors and emerging non-volatile memories, including materials fundamentals, process technologies, device physics, novel device architectures, and neuromorphic computing applications. Papers related to device and material technologies for advanced CMOS and emerging non-volatile memories for neuromorphic computing applications are solicited, including the following:

- (1) Advanced CMOS device architectures for high performance, ultralow-power consumption, and reliability improvement;
- (2) Emerging materials and advanced process technologies for high-mobility channel, gate stack formation, S/D contact, and junction;
- (3) Device physics, novel characterization methods, TCAD simulation, and ab initio calculation for advanced CMOS and emerging non-volatile memories;
- (4) Conventional memories and emerging memories such as ReRAM, MRAM, PCRAM, and FeRAM;
- (5) Memory device physics, reliability, and modeling;
- (6) Synaptic devices for neuromorphic computing applications.











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Message from the Editor-in-Chief

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